Three-quadrant triacs high commutation

Rev. 01 — 5 December 2005

Product data sheet

1. Product profile

1.1 General description

Passivated high voltage, high commutation triac in a SOT404 surface mounted device, plastic package. This triac is intended for use in motor control circuits where high blocking voltage, high static and dynamic dV/dt as well as high dl/dt can occur. This device will commutate the full rated RMS current at the maximum rated junction temperature without the aid of a snubber.

1.2 Features



2. Pinning information

Table 1:	Pinning		
Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)		
2	main terminal 2 (T2)	mb	T2-T1
3	gate (G)		`G sym051
mb	mounting base; main terminal 2		

SOT404 (D2PAK)



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3. Ordering information

Table 2: Ordering information						
Type number	Package					
	Name	Description	Version			
BTA208B-1000C	D2PAK	plastic single-ended surface mounted package; 3 leads (one lead cropped)	SOT404			

4. Limiting values

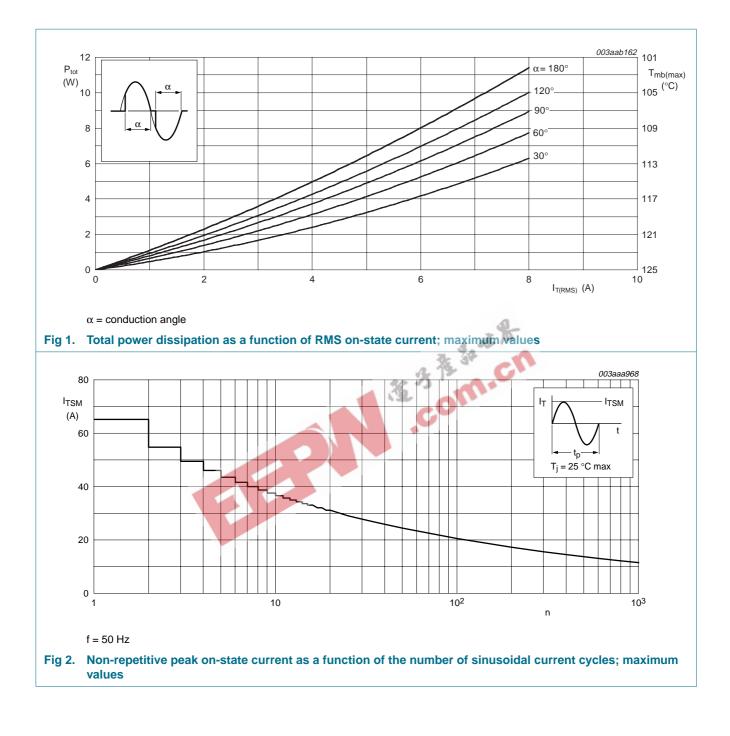
Table 3:Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DRM}	repetitive peak off-state voltage		-	1000	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 102 °C; see <u>Figure 4</u> and <u>5</u>		8	А
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_j = 25 \text{ °C prior}$ to surge; see <u>Figure 2</u> and <u>3</u>	1 /5-		
		t = 20 ms	C	65	А
		t = 16.7 ms 🌠 🔷 👘	-	71	А
l ² t	I ² t for fusing	t = 10 ms	-	21	A ² s
dl _T /dt	rate of rise of on-state current	$I_{TM} = 12 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	100	A/μs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

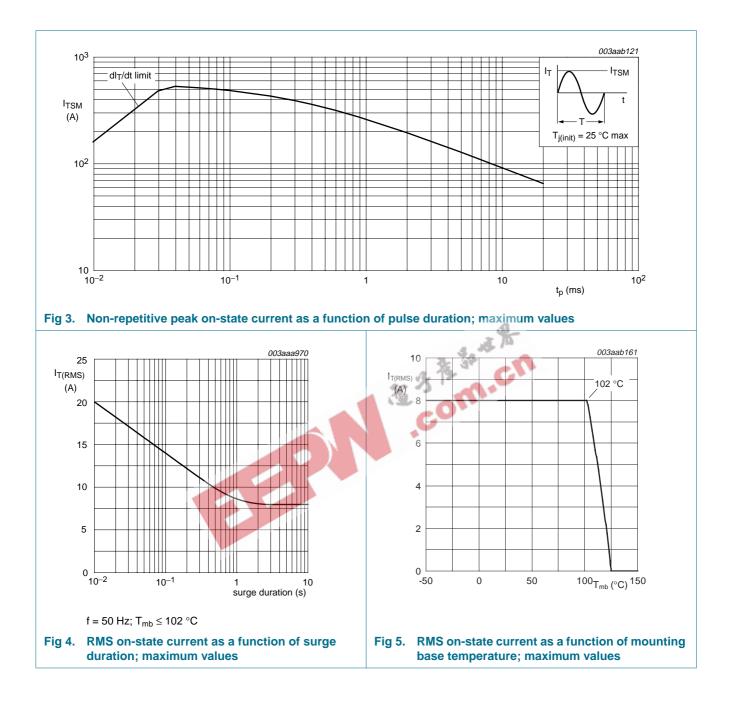
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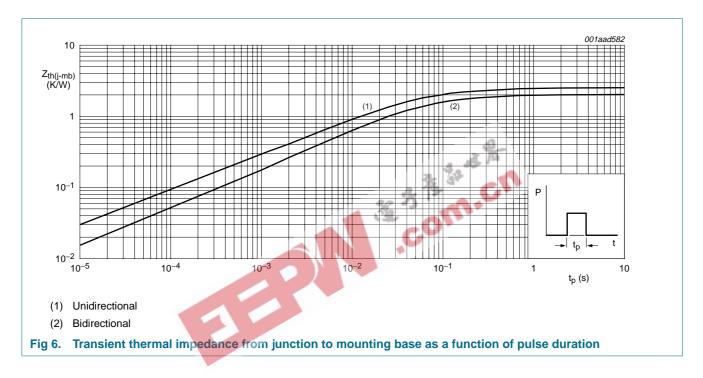


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5. Thermal characteristics

Table 4:	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	full cycle; see Figure 6	-	-	2	K/W
		half cycle; see Figure 6	-	-	2.4	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	minimum footprint	-	55	-	K/W



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Characteristics 6.

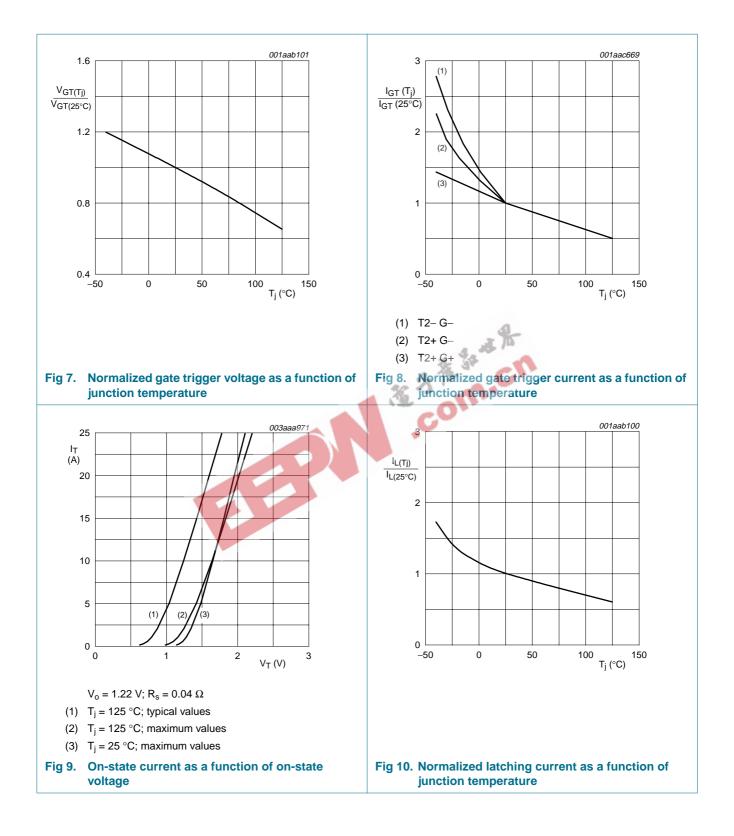
Table 5:	Characteristics
$T_{1} = 25 \circ C$	unlocs otherwise sp

Table 5: $T_j = 25 \circ C \iota$	Characteristics Inless otherwise specified	ł.				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_D = 12 V; I_T = 0.1 A; see Figure 8$	1]			
		T2+ G+	2	6	35	mA
		T2+ G–	2	13	35	mA
		T2- G-	2	23	35	mA
IL	latching current	V _D = 12 V; I _{GT} = 0.1 A; see Figure 10				
		T2+ G+	-	25	50	mA
		T2+ G–	-	48	75	mA
		T2– G–	-	30	50	mA
I _H	holding current	V _D = 12 V; I _{GT} = 0.1 A; see Figure 11	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	20	50	mA
V _T	on-state voltage	I _T = 10 A; see <u>Figure 9</u>	ac - 34	1.3	1.65	V
V _{GT}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ see } Figure 7$	12	0.7	1.5	V
		$V_D = 400 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 125 \ ^\circ\text{C}$	0.25	0.4	-	V
I _D	off-state current	$V_D = V_{DRM(max)}; T_j = 125 $ °C		0.1	0.5	mA
Dynamic o	haracteristics					
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 67 \% V_{DRM(max)};$ T _j = 125 °C; exponential waveform; gate open circuit	1000	4000	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_{DM} = 400 \text{ V}; T_j = 125 \text{ °C};$ $I_{T(RMS)} = 8 \text{ A};$ without snubber; gate open circuit; see Figure 12	12	32	-	A/ms
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 12 \text{ A}; \text{V}_{\text{D}} = \text{V}_{\text{DRM}(\text{max})}; \\ I_{\text{G}} &= 0.1 \text{A}; \text{d}\text{I}_{\text{G}}/\text{d}\text{t} = 5 \text{A}/\mu\text{s} \end{split}$	-	2	-	μs

[1] Device will not trigger in the T2– G+ quadrant.

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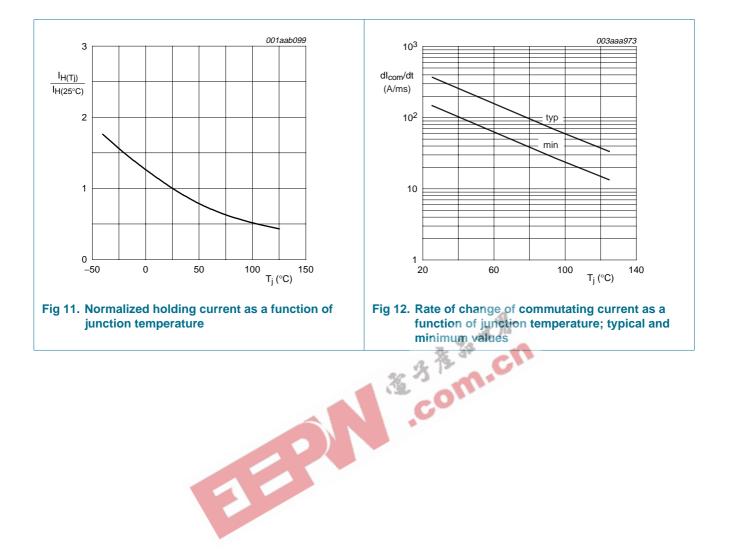
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7. Package outline

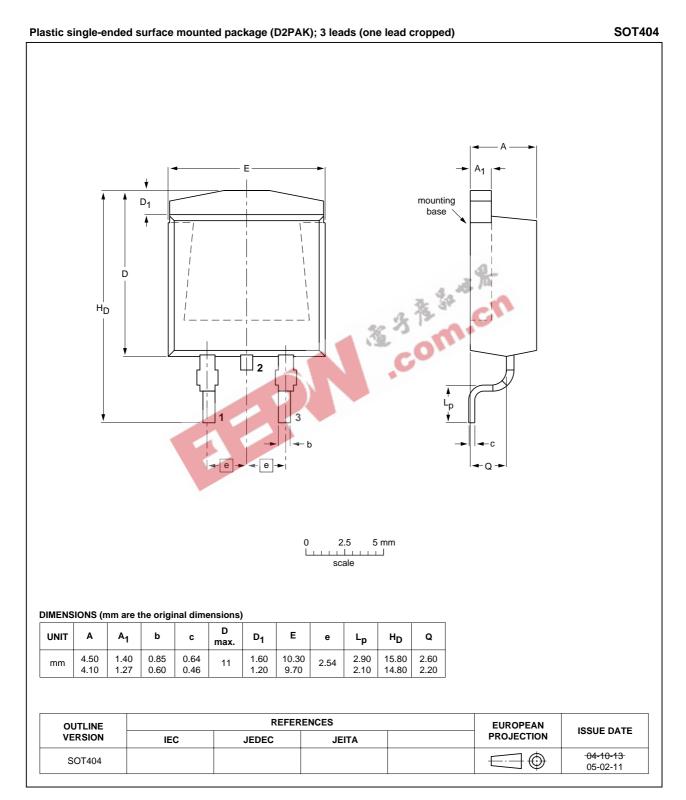


Fig 13. Package outline SOT404 (D2PAK)

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8. Revision history

Table 6: Revision his	Revision history				
Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BTA208B-1000C_1	20051205	Product data sheet	-	-	-



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9. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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